2SB1361

Silicon PNP triple diffusion planar type

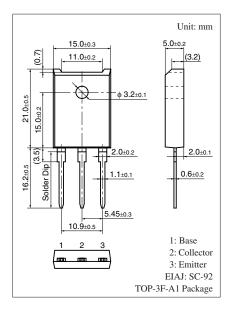
For high power amplification

■ Features

- \bullet Excellent collector current I_C characteristics of forward current transfer ratio h_{FE}
- Wide safe operation area
- High transition frequency f_T
- Full-pack package which can be installed to the heat sink with one screw

■ Absolute Maximum Ratings $T_C = 25$ °C

Parameter	Symbol	Rating	Unit
Collector-base voltage (Emitter open)	V _{CBO}	-150	V
Collector-emitter voltage (Base open)	V _{CEO}	-150	V
Emitter-base voltage (Collector open)	V_{EBO}	-5	V
Collector current	I_C	-9	A
Peak collector current	I_{CP}	-15	A
Collector power dissipation	P _C	100	W
$T_a = 25$ °C		3	
Junction temperature	T_{j}	150	°C
Storage temperature	T _{stg}	-55 to +150	°C



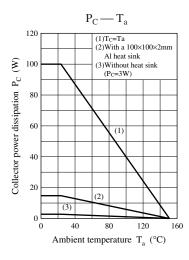
■ Electrical Characteristics $T_C = 25$ °C ± 3 °C

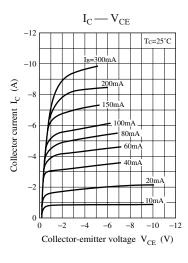
Parameter	Symbol	Conditions	Min	Тур	Max	Unit
Base-emitter voltage	V_{BE}	$V_{CE} = -5 \text{ V}, I_{C} = -7 \text{ A}$			-1.8	V
Collector-base cutoff current (Emitter open)	I_{CBO}	$V_{CB} = -150 \text{ V}, I_E = 0$			-50	μΑ
Emitter-base cutoff current (Collector open)	I_{EBO}	$V_{EB} = -3 \text{ V}, I_{C} = 0$			-50	μΑ
Forward current transfer ratio	h _{FE1}	$V_{CE} = -5 \text{ V}, I_{C} = -20 \text{ mA}$	20			_
	h _{FE2} *	$V_{CE} = -5 \text{ V}, I_{C} = -1 \text{ A}$	60		200	
	h _{FE3}	$V_{CE} = -5 \text{ V}, I_{C} = -7 \text{ A}$	20			
Collector-emitter saturation voltage	V _{CE(sat)}	$I_C = -7 \text{ A}, I_B = -0.7 \text{ A}$			-2.0	V
Transition frequency	f_T	$V_{CE} = -5 \text{ V}, I_{C} = -0.5 \text{ A}, f = 1 \text{ MHz}$		15		MHz
Collector output capacitance	C _{ob}	$V_{CB} = -10 \text{ V}, I_E = 0, f = 1 \text{ MHz}$		270		pF
(Common base, input open circuited)						

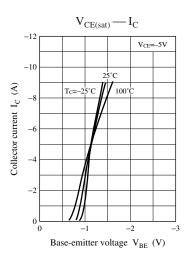
Note) 1. Measuring methods are based on JAPANESE INDUSTRIAL STANDARD JIS C 7030 measuring methods for transistors.

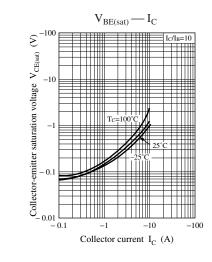
2. *: Rank classification

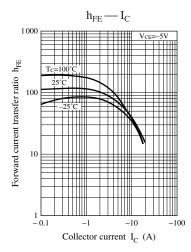
Rank	Q	S	Р
h_{FE2}	60 to 120	80 to 160	100 to 200

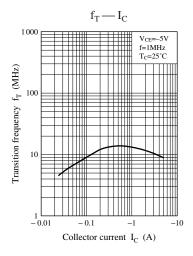


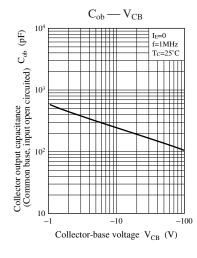


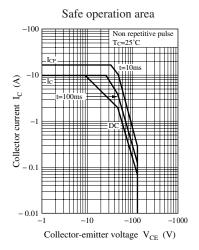


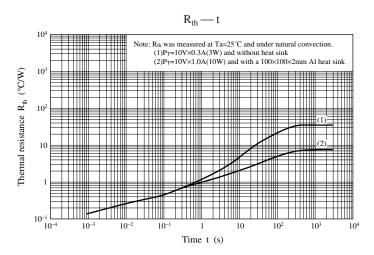












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